APPLICATION SPECIFIC APPARATUS FOR DISSIPATING HEAT FROM MULTIPLE ELECTRONIC COMPONENTS

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ABSTRACT

An application specific heat sink assembly is presented wherein a heat-dissipating substrate is selected of a particular size, shape and material in order to meet predetermined heat-dissipating requirements and more than one heat-dissipating stud is selected or formed of particular sizes, shapes and materials in order to meet predetermined requirements. The heat-dissipating substrate and heat-dissipating studs form a heat sink assembly having application specific features selected to optimize the heat-dissipating, CTE matching, environmental resistance requirements, low mass requirements, size, machinability, cost structure and other desirable features of a particular application for dissipating heat from multiple electronic components.
FIG. 1
FIG. 3
PROVIDE HEAT DISSIPATION SUBSTRATE

ATTACH HEAT DISSIPATING STUD WITH DESIRED FEATURES TO HEAT DISSIPATION SUBSTRATE

ATTACH HEAT GENERATING COMPONENT TO STUD

FIG. 4
PROVIDE HEAT DISSIPATION SUBSTRATE WITH ALIGNMENT CAVITY

ATTACH HEAT DISSIPATING STUD INTO ALIGNMENT CAVITY

ATTACH HEAT GENERATING COMPONENT TO STUD

FIG. 5
PROVIDE HEAT DISSIPATION SUBSTRATE

ATTACH HEAT DISSIPATION LAYER WITH DESIRED FEATURES TO HEAT DISSIPATION SUBSTRATE

SHAPE HEAT DISSIPATION LAYER INTO HEAT DISSIPATING STUD

ATTACH HEAT GENERATING COMPONENT TO HEAT DISSIPATING STUD

FIG. 6
1010 PROVIDE HEAT-DISSIPATION SUBSTRATE

1020 ATTACH A FIRST HEAT-DISSIPATING STUD WITH APPLICATION SPECIFIC FEATURES TO HEAT-DISSIPATION SUBSTRATE

1030 ATTACH A FIRST HEAT GENERATING COMPONENT TO BE COOLED TO FIRST HEAT-DISSIPATING STUD

1040 ATTACH A SECOND HEAT-DISSIPATING STUD WITH APPLICATION SPECIFIC FEATURES TO HEAT-DISSIPATION SUBSTRATE

1050 ATTACH A SECOND HEAT GENERATING COMPONENT TO BE COOLED TO SECOND HEAT-DISSIPATING STUD

FIG. 10
APPLICATION SPECIFIC APPARATUS FOR DISSIPATING HEAT FROM MULTIPLE ELECTRONIC COMPONENTS

BACKGROUND OF THE INVENTION

[0001] Electronic components, such as integrated circuits or printed circuit boards, are becoming more and more common in various devices. For example, central processing units, interface, graphics, and memory circuits typically comprise several integrated circuits. During normal operations, many electronic components, such as integrated circuits, generate significant amounts of heat. If the heat generated during the operation of these and other devices is not removed, the electronic components or other devices near them may overheat, resulting in damage to the components or degradation of component performance.

[0002] In order to avoid such problems caused by over heating, heat sinks or other heat-dissipating devices are often used with electronic components to dissipate heat. One must balance the heat-dissipating requirements of a heat sink with other factors. Heat sinks may crack, damage or separate from the electronic components they are attached to if the heat sink has a coefficient of thermal expansion significantly different from the electronic component. Also, many heat sink materials are relatively heavy. If the electronic component the heat sink is attached to is subjected to vibration or impact, the weight of the heat sink attached to the electronic component may crack, damage or cause the heat sink to separate from the electronic component to which it is attached.

[0003] Frequently, more than one electronic component on a printed circuit board, multi-chip module or electronic system requires heat dissipation. It would be advantageous for more than one component to be able to utilize a single heat-dissipating device, in order to optimize system cost, weight, size, and other features. However, different die on a printed circuit assembly or within a multi-chip module may have different coefficients of thermal expansion or heat dissipation requirements. It would be advantageous to provide a heat-dissipating device that is capable of accommodating various different requirements to more than one device requiring heat-dissipation.

[0004] Some materials provide good thermal conductivity, but are difficult to shape, expensive, heavy or have other less desirable features to a particular heat-dissipating situation.

[0005] Accordingly, there exists a need in the industry for the ability to optimize heat dissipation, weight, cost, machinability and other features of heat-dissipating devices and to provide a single heat-dissipating device to more than one die or component in an electronic assembly.

SUMMARY OF THE INVENTION

[0006] An apparatus and method for optimizing heat dissipation, CTE matching, weight, cost, machinability or other features of a heat dissipation device.

[0007] The apparatus may comprise a application specific heat sink device for dissipating heat from more than one electronic component, the application specific heat sink device may have a heat-dissipating substrate selected for one or more of its size, shape, mass, cost, thermal conductivity, or environmental resistance properties, and more than one heat-dissipating studs, each selected for its CTE and machinability properties, such that each heat-dissipating stud may be attached to the heat-dissipating substrate such that an electronic component may be attached to each of the heat-dissipating studs.

[0008] A method for manufacturing an application specific heat sink device for dissipating heat from more than one electronic component, which may include selecting or forming a heat-dissipating substrate; forming more than one heat-dissipating stud, such that each of the heat-dissipating studs may be shaped and sized to mate with an electronic device to be cooled; and attaching each of the heat-dissipating studs to the substrate. An electronic device to be cooled may be attached to each heat-dissipating stud.

BRIEF DESCRIPTION OF THE DRAWINGS

[0009] A more complete appreciation of this invention, and many of the attendant advantages thereof, will be readily apparent as the same becomes better understood by reference to the following detailed description when considered in conjunction with the accompanying drawings in which like reference symbols indicate the same or similar components, wherein:

[0010] FIG. 1 illustrates a first embodiment of a heat-dissipating device in accordance with the present invention;

[0011] FIG. 2 illustrates a second embodiment of a heat-dissipating device in accordance with the present invention;

[0012] FIG. 3 illustrates a third embodiment of a heat-dissipating device in accordance with the present invention;

[0013] FIG. 4 illustrates a flow chart for manufacturing a heat-dissipating device in accordance with the first embodiment of the present invention;

[0014] FIG. 5 illustrates a flow chart for manufacturing a heat-dissipating device in accordance with the second embodiment of the present invention;

[0015] FIG. 6 illustrates a flow chart for manufacturing a heat-dissipating device in accordance with the third embodiment of the present invention;

[0016] FIG. 7 illustrates a top plan view of an integrated circuit device package according to a fourth embodiment of the invention prior to encapsulation;

[0017] FIG. 8 illustrates a cross-sectional view of the integrated circuit device of FIG. 7 taken along line 8-8;

[0018] FIG. 9 illustrates a fifth embodiment of a heat-dissipating device for dissipating heat from more than one component in accordance with the present invention;

[0019] FIG. 10 illustrates a flow chart for manufacturing a heat-dissipating device in accordance with the fifth and sixth embodiments of the present invention; and

[0020] FIG. 11 illustrates a cross-sectional view of more than one integrated circuits attached to a heat-dissipating device prior to encapsulation in accordance with a sixth embodiment of the present invention.

DETAILED DESCRIPTION

[0021] As shown in the drawings for purposes of illustration, the present invention relates to techniques for provid-
ing a heat-dissipating device in which the various features of the device, e.g. thermal conductivity, precise tolerances, CTE matching with the part to be cooled, environmental resistance, low mass, good bondability, cost, machinability, etc., may be selectively optimized. Optimizing various features of a heat sink device may be accomplished with a heat sink of more than one material, creating an application specific heat sink structure capable of meeting different requirements in different locations more readily than a monolithic heat sink structure.

[0022] Turning now to the drawings, FIG. 1 illustrates a heat dissipation device according to a first embodiment of the present invention. A heat dissipation substrate 110 is provided. The heat dissipation substrate 110 may be selected from any known heat sink material, alloy or combination thereof, such as Aluminum Silicon Carbide, Copper, Aluminum, carbon/metall composite, ceramic or other known heat sink material. By way of example only, AlSiC may be selected for its heat conducting qualities and low weight. A heat-dissipating stud 120 may be formed by stamping, machining, etching or laser cutting from any known heat sink material, alloy or combination thereof, such as copper, tungsten, molybdenum, aluminum, copper/molybdenum/copper or other known heat sink material.

[0023] Heat stud 120 may be selected in order to have a CTE (coefficient of thermal expansion) that is relatively close to the device (integrated circuit chip, integrated circuit package, integrated circuit module, printed circuit board, etc.) to which it is to be attached. As shown in the flow chart in FIG. 4, the heat dissipation stud 120 may be attached to the surface 180 of the heat dissipation substrate 110 at a predetermined location 130 by any known means of attachment, such as brazing, soldering, adhesive bonding, press fit, screws, rivets, welding, cold diffusion under high pressure, diffusion bonding, or a thermally conductive metallic adhesive. The heat-dissipating stud 120 is precisely shaped by means of machining, stamping, etching or laser cutting and attached to the heat dissipation substrate 110 at a predetermined location 130.

[0024] As the application specific heat sink of the present invention is versatile, various heat-dissipating substrates 110 of various materials and sizes may be kept on hand. Various heat-dissipating studs 120 of various materials and sizes may be kept on hand. Thus, the manufacturer of the device to be cooled (one exemplary embodiment shown in FIGS. 7-8) may select the substrate 110 and stud 120 for a particular heat-dissipating application by feature requirements, cost, low mass, good thermal conductivity, precise tolerances, etc. In such a case, as shown in FIG. 4, the manufacturer may select 410 the substrate 110, select the stud 120 and select an appropriate attachment method 420 as required by the particular application in order to optimize the heat sink features to the application, while minimizing heat sink costs. The device to be cooled may be attached to the stud 420. It should be noted, that the stud 120 might be attached to the device to be cooled before the stud 120 is attached to the substrate 110.

[0025] Alternatively, the manufacturer may keep various heat-dissipating substrates 110 of varying materials and sizes on hand or order from a supplier. Once the heat-dissipating substrate 110 is selected 410 for a particular application, a customized heat-dissipating stud 120 may be fabricated to specific size, thermal conductivity requirements, etc. After the stud 120 is manufactured, it may be attached 420 by any attachment method appropriate to the application. This embodiment may permit the substrate 110 to be of a material, alloy, or composite that is not readily machinable, but has other desirable heat sink features, such as good thermal conductivity, inexpensive, low mass, etc., while the stud 120 may provide other features, such as improved CTE matching with the device to be cooled, more precise machinability for sizing to match the device to be cooled, etc. The studs may also be used to obtain relative CTE matching with each respective die. It should be noted that precise CTE matching is not usually required, it is sufficient to have relatively close CTE's, as disclosed in U.S. Pat. No. 5,886,407, Polese et al., which is hereby incorporated in this Specification by reference.

[0026] FIG. 2 shows a heat-dissipating device according to a second embodiment of the present invention. In FIG. 2, a heat-dissipating substrate 210 is provided with an alignment cavity 230 for aligning and attaching a heat-dissipating stud 220. The heat-dissipating substrate 210 may be formed by any known method, such as, machining or stamping. The cavity 230 may be formed in substrate 210 by machining or coining/stamping. As shown in the flow chart of FIG. 5, once the substrate is selected 510, the stud 220 may be attached 520 in the alignment cavity 230 by means of brazing, soldering, adhesive bonding, diffusion bonding, cold diffusion under high pressure, a thermally conductive metallic adhesive or other known attachment means. The device to be cooled (not shown) may be attached 530 to the stud 220 by means of any standard die attach method, including epoxy or eutectic die attach. This embodiment may provide for more precise alignment of the stud 220 on the substrate 210.

[0027] FIG. 3 shows a heat-dissipating device according to a third embodiment of the present invention. In FIG. 3, a heat-dissipating substrate 310 is provided of a predetermined size and material, metal, alloy or composite for precise requirements of a particular heat-dissipating application. As shown in FIG. 6, after the substrate is selected 610, a layer 390 of a material selected to form a heat-dissipating stud 320 is attached 620 by any known attachment means, such as brazing, soldering, adhesive bonding, diffusion bonding, vacuum hot pressing, etc. After the layer 390 is attached, a stud 320 of a predetermined size for mating with the device to be cooled is formed 630 by machining, laser cutting, chemical etching, or other known process at a predetermined location 330 on a top surface of layer 390. After the heat-dissipating stud 320 is formed in layer 390, the device to be cooled may be attached 640. The heat-dissipating stud is shaped to fit the electronic device to be cooled.

[0028] An application of the above-described heat-dissipating assembly elements in an integrated circuit device-cooling situation will now be described with reference to FIGS. 7 and 8. The integrated circuit device 741 comprises an electrical interconnect support structure 742 made of one or more layers of relatively inexpensive dielectric material such as polyamide or other polymer dielectrics, or epoxy materials having a relatively high CTE. The support structure 742 supports a heat-dissipating substrate 743 chosen for application specific qualities as described previously with respect to substrates 110, 210, and 310 and FIGS. 1-8.
A heat-dissipating stud 745 rising from the upper surface 746 of the heat-dissipating substrate 743 supports a microchip or die 744. The heat-dissipating stud 745 is manufactured separately from the heat-dissipating substrate 743 and then attached to the heat-dissipating substrate 743 by brazing, resistance welding, ultrasonic welding, pressing, i.e., cold fusion under high pressure, soldering, adhesive bonding, press fit, screws, rivets, diffusion bonding, or with use of an adhesion layer 751 of thermally conductive adhesive material or other thin adhesion material of a thickness to be determined by thermal performance requirements. A series of wire-bonds 747 connect contact points on the die 744 to metallization 748 patterned onto the surface 749 or within the body of support structure 742. The metallization connects to a plurality of leads 750 extending outward from the integrated circuit device 741. Heat-dissipating substrate 743 may be sized/shaped such that it may form part of the encapsulation structure, not shown.

It should be noted that in order to reduce heat-dissipating expenses in integrated circuit devices, the heat-dissipating substrate 743 may be selected from various generic materials, sizes and shapes, selected for it heat-dissipating qualities, low mass, environmental conditions, resistance, price, etc. In order to distribute and reduce the mechanical stress at the junction of the various components of the device, the materials used for the support structure 742 are selected to have intermediate CTE's between the heat-dissipating substrate 743 and the metallization 748. The heat-dissipating stud 745 is selected from various materials to provide an intermediate CTE between the heat-dissipating substrate 743 and the integrated circuit die 744, along with other desired application specific features such as customizing of CTE matching to die, sizing, environment resistance, price, mass, etc.

The present invention may permit an end user to precisely select various features of a heat sink device to a particular application. The main body of the heat sink, or the substrate, may be of a generic size, shape and material to optimize selected features of the heat sink, such as thermal conductivity, low mass, inexpensive material, cheaper manufacturing processes, environmental resistance, bondability, etc. While the interface surface, or slug, may be selected of a material, size and shape or made customized to the particular application, in order to optimize selected features, such as improved CTE matching with the device to be cooled, bondability, machinability to precise tolerances, etc.

It should be noted that the application specific shape of the heat-dissipating stud might be formed before or after it is attached to the heat-dissipating substrate. Also, the heat-dissipating stud may be attached to the device to be cooled before or after it is attached to the heat-dissipating substrate. Also, although FIGS. 7-8 illustrate an integrated circuit device 744 being cooled, the present invention is just as applicable to printed circuit boards, multi-chip modules, prepackaged devices, etc. without deviating from the basic concepts of the present invention.

Embodiments one-four are also applicable in a situation in which the heat-dissipating substrate may be utilized to cool more than one integrated circuit, die, printed circuit assembly or components in a multi-chip module. Basically, more than one electronic component in an assembly may utilize a single heat-dissipating substrate with different heat-dissipating studs being interposed between each electronic component to be cooled and the heat-dissipating substrate.

By way of exemplary illustration only, FIG. 9 shows a heat-dissipating apparatus according to a fifth embodiment of the present invention, in which a first heat-dissipating stud 920 and a second heat-dissipating stud 930 are attached to a heat-dissipating substrate 910. Heat-dissipating studs 920 and 930 are selected or formed from similar or different materials for specific desired features, such as CTE matching with first and second die or electronic assemblies (not shown), as taught herein with respect to FIGS. 1-8.

As shown in FIG. 10, heat-dissipating apparatus 900 may be manufactured by selecting from various generic substrates of varying sizes, shapes and materials or forming a substrate 910 from a specific heat-dissipating material selected for application specific features as taught with respect to FIGS. 1-8 (1010). Heat-dissipating studs 920 and 930 may be formed of similar or different materials, selected for applications specifically desired features as taught herein with respect to FIGS. 1-8 and attached to substrate 910 (1020 and 1040). Electronic components (not shown in FIG. 9) are attached to heat-dissipating studs 920 and 930. These steps may be formed in any order and any or all of the substrate 910 or studs 920 and 930 may be generic components on hand and selected and assembled for a specific application or custom fabricated to a specific application.

It should be noted that studs 920 and 930 might be formed by similar or different methods and of similar or different materials, depending on the specific desired features or requirements of the electronic component to be attached to each stud. There may be more than two heat-dissipating studs attached between the heat-dissipating substrate 910 and individual heat-generating devices or areas of an integrated circuit or multi-chip module. Also, heat-dissipating studs may be attached on both the top and the bottom surface of the heat-dissipating substrate, limited only by proximity, heat-dissipation requirements, size, weight and other devices in an assembly with heat dissipation requirements.

FIG. 11 illustrates an electronic assembly 1141 comprising an electrical interconnect support structure 1124 made of one or more layers of dielectric material such as polyamide or other polymer dielectric or epoxy materials. The support structure 1142 is attached to a heat-dissipating substrate 1143 made of a heat-dissipating material chosen for application specific qualities and features as described herein with respect to FIGS. 1-8.

Two or more microchips or die 1144 and 1154 are supported by heat-dissipating studs 1145 and 1155, respectively, rising from the upper surface of heat-dissipating substrate 1143. Heat-dissipating studs 1145 and 1155 may be manufactured separately from heat-dissipating substrate 1143 and attached to heat-dissipating substrate 1143 by brazing, resistance welding, ultrasonic welding, pressing, i.e., cold fusion under high pressure, soldering, adhesive bonding, press fit, screws, rivets, diffusion bonding or by and adhesion layer (not shown) of thermally conductive adhesive material or other thin adhesion material of a thickness to be determined by thermal performance require-
ments. A series of wire-bonds 1147 connect contact points on the die 1144 and 1154 to metallization layer or layers 1148 patterned on the surface or within the body of support structure 1142. The metallization connects to a plurality of leads 1150 extending from the electronic assembly or multi-chip module 1141. Heat-dissipating substrate 1143 may be sized/shaped such it may form part of an encapsulation structure for the electronic assembly (not shown).

[0039] In order to reduce the cost of the electronic assembly or multi-chip module 1141, the heat dissipating substrate 1143 may be selected from various generic materials, sizes and shapes, selected for its thermal conductivity, low mass, environmental resistance, price, etc. In order to distribute and reduce the mechanical stress at the junction of the various components of the assembly, the materials used for the support structure 1142 may be selected to have intermediate CTEs between the heat-dissipating substrate 1143 and the metallization layer 1148. The heat-dissipating studs 1145 and 1155 may be selected from various materials to provide an intermediate CTE between the heat-dissipating substrate 1143 and the die 1144 and 1154, along with other desired application specific features such as customizing of CTE matching to die, sizing, environment resistance, price, mass, machinability, etc.

[0040] Although this preferred embodiment of the present invention has been disclosed for illustrative purposes, those skilled in the art will appreciate that various modifications, additions and substitutions are possible, without departing from the scope of the invention, resulting in equivalent embodiments that remain within the scope of the appended claims. For example, the generic heat-dissipating substrate may also be a heat-dissipating substrate with fins or other common heat-dissipating physical features.

What is claimed is:

1. An application specific heat sink device for dissipating heat from more than one electronic component, the application specific heat sink device comprising:

a heat-dissipating substrate selected for one or more of the following properties: size, shape, mass, cost, thermal conductivity, environmental resistance; and

more than one heat-dissipating stud, wherein each heat-dissipating stud is selected for its CTE and machinability properties, wherein each heat-dissipating stud is attached to the heat-dissipating substrate such that an electronic component may be attached to each heat-dissipating stud.

2. The application specific heat sink device in accordance with claim 1, wherein the heat-dissipating substrate comprises Aluminum Silicon Carbide.

3. The application specific heat sink device in accordance with claim 1, wherein the heat-dissipating substrate comprises a carbon-metal alloy.

4. The application specific heat sink device in accordance with claim 1, wherein the heat-dissipating substrate comprises a ceramic.

5. The application specific heat sink device in accordance with claim 1, wherein the heat-dissipating substrate includes fins.

6. The application specific heat sink device in accordance with claim 1, wherein each heat-dissipating stud comprises a material with a CTE relatively close to the CTE of the electronic component to be attached to it.

7. The application specific heat sink device in accordance with claim 1, wherein each heat-dissipating stud comprises a material with a CTE relatively intermediate between the CTE of the electronic component to be attached to it and the heat-dissipating substrate.

8. The application specific heat sink device in accordance with claim 1, wherein each heat-dissipating stud comprises a metal, a metal alloy or combinations thereof.

9. An application specific heat sink device in accordance with claim 1, wherein the heat-dissipating substrate comprises one or more cavities on a first surface, wherein at least one heat-dissipating stud is attached to the heat-dissipating substrate within the one or more cavities on the first surface of the heat-dissipating substrate, wherein the cavity provides an alignment means.

10. An application specific heat sink device in accordance with claim 1, wherein one or more of the heat-dissipating studs is formed by forming a layer of application specifically selected material to a top surface of the heat-dissipating substrate and then forming one or more of the heat-dissipating studs from the application specifically selected material.

11. An application specific heat sink device in accordance with claim 1, wherein the heat-dissipating substrate is formed by machining, laser cutting or chemical etching the one or more heat-dissipating studs from the layer of application specifically selected material.

12. A method for manufacturing an application specific heat sink device, comprising:

selecting a heat-dissipating substrate;

forming more than one heat-dissipating stud, wherein each heat-dissipating stud is shaped and sized to mate with an electronic device to be cooled; and

attaching the more than one heat-dissipating studs to predetermined locations on the heat-dissipating substrate.

13. The method in accordance with claim 12, wherein the heat-dissipating substrate comprises Aluminum Silicon Carbide.

14. The method in accordance with claim 12, wherein each of the more than one heat-dissipating studs comprises a material selected to have a relatively close CTE with the electronic device to be attached to it.

15. The method in accordance with claim 12, wherein each of the more than one heat-dissipating studs comprises a material selected to have an intermediate CTE between the heat-dissipating substrate and a device to be attached to it.

16. The method in accordance with claim 12, wherein the heat-dissipating substrate is selected for one or more of the following qualities, thermal conductivity, environmental resistance, low mass, inexpensive price, or bondability.

17. The method in accordance with claim 12, further comprising the step of forming one or more cavities in a top surface of the heat-dissipating substrate; wherein one or more of the two or more heat-dissipating studs is attached within the one or more cavities formed on the heat-dissipating substrate.

18. The method in accordance with claim 12, wherein the heat-dissipating substrate includes fins.